

Automotive P-Channel 80 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY	
V_{DS} (V)	- 80
$R_{DS(on)}$ (Ω) at $V_{GS} = - 10$ V	0.025
$R_{DS(on)}$ (Ω) at $V_{GS} = - 4.5$ V	0.031
I_D (A)	- 50
Configuration	Single

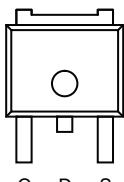
FEATURES

- TrenchFET® Power MOSFET
- AEC-Q101 Qualified^d
- 100 % R_g and UIS Tested
- Material categorization:
For definitions of compliance please see
www.vishay.com/doc?99912



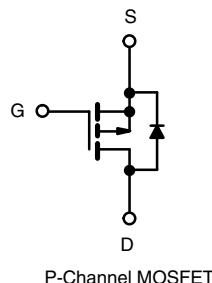
RoHS
COMPLIANT
HALOGEN
FREE

TO-252



Drain Connected to Tab

Top View



P-Channel MOSFET

ORDERING INFORMATION

Package	TO-252
Lead (Pb)-free and Halogen-free	SQD50P08-25L-GE3

ABSOLUTE MAXIMUM RATINGS ($T_C = 25$ °C, unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNIT
Drain-Source Voltage	V_{DS}	- 80	V
Gate-Source Voltage	V_{GS}	± 20	
Continuous Drain Current	I_D	- 50	A
		- 28	
Continuous Source Current (Diode Conduction) ^a	I_S	- 50	
Pulsed Drain Current ^b	I_{DM}	- 120	
Single Pulse Avalanche Current	I_{AS}	- 45	mJ
Single Pulse Avalanche Energy	E_{AS}	100	
Maximum Power Dissipation ^b	P_D	136	W
		45	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	- 55 to + 175	°C

THERMAL RESISTANCE RATINGS

PARAMETER	SYMBOL	LIMIT	UNIT
Junction-to-Ambient	R_{thJA}	50	°C/W
Junction-to-Case (Drain)	R_{thJC}	1.1	

Notes

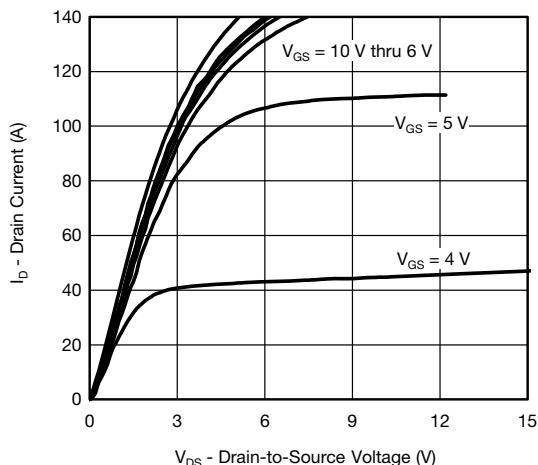
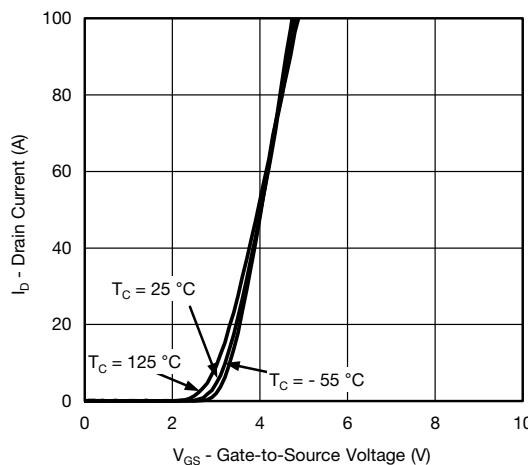
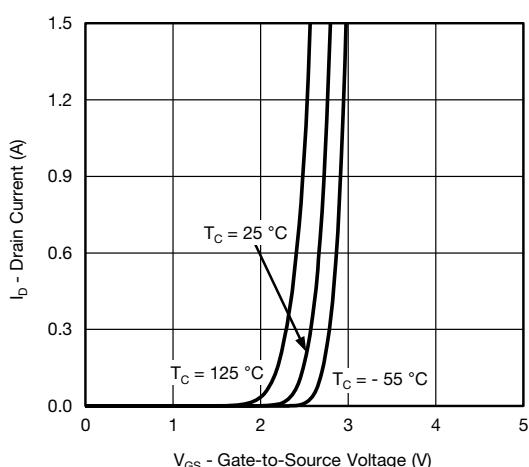
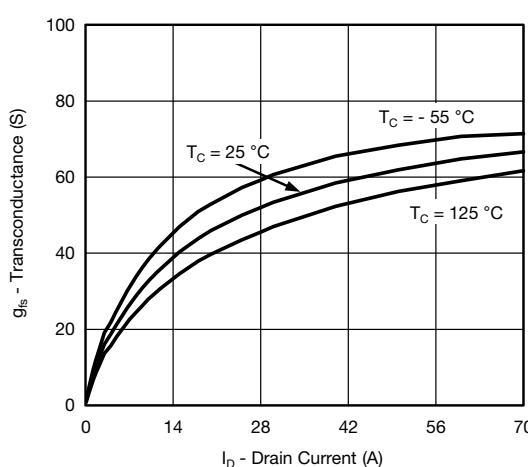
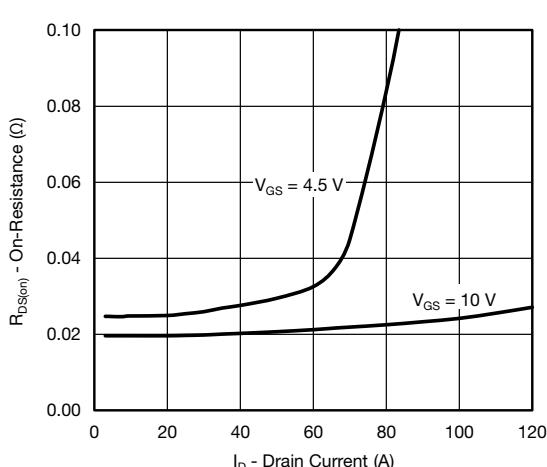
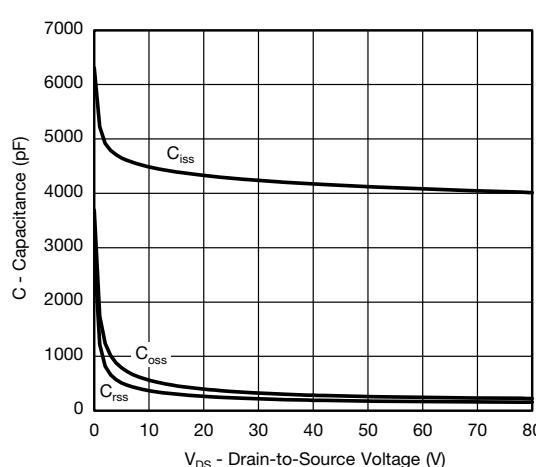
- Package limited.
- Pulse test; pulse width ≤ 300 μ s, duty cycle ≤ 2 %.
- When mounted on 1" square PCB (FR-4 material).
- Parametric verification ongoing.

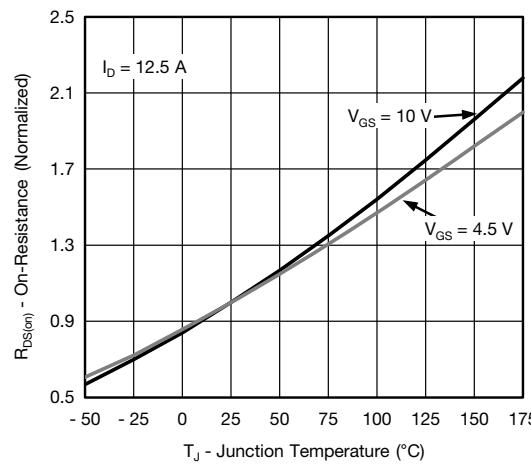
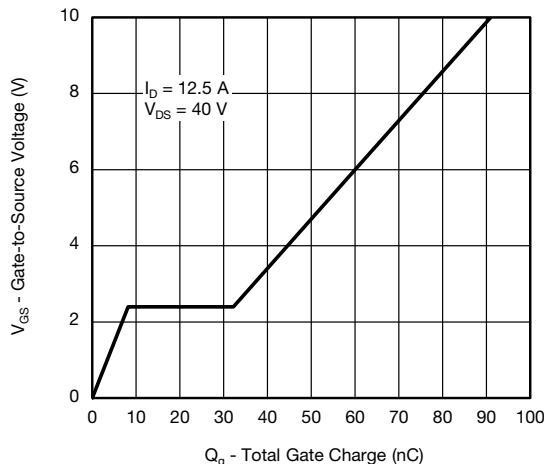
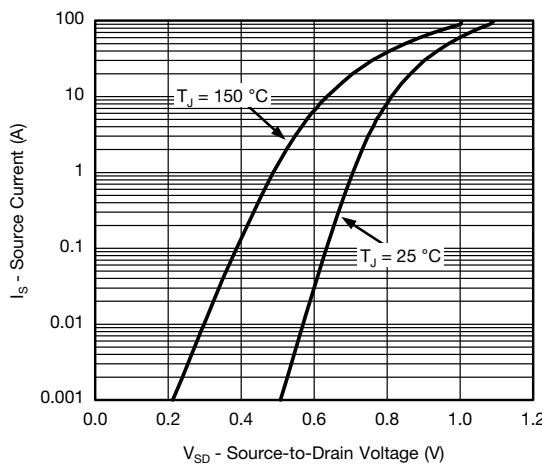
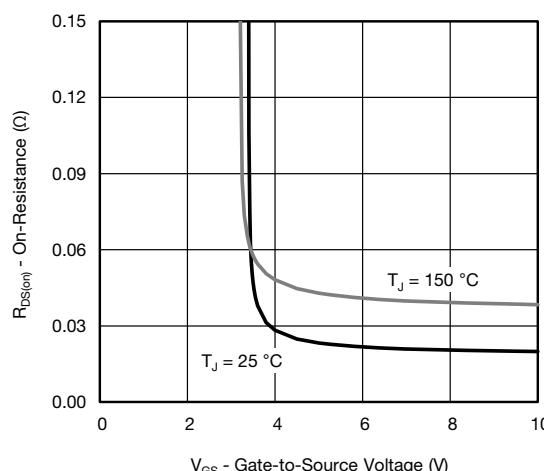
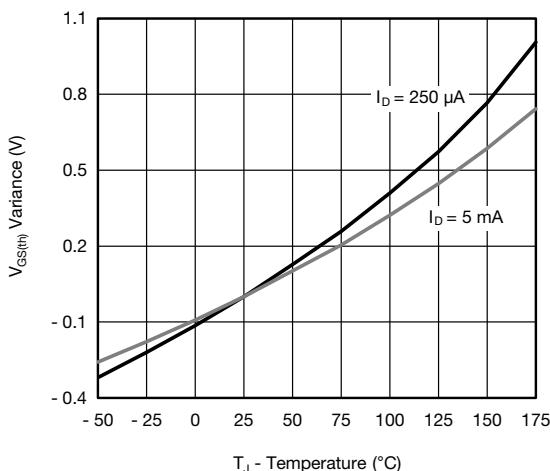
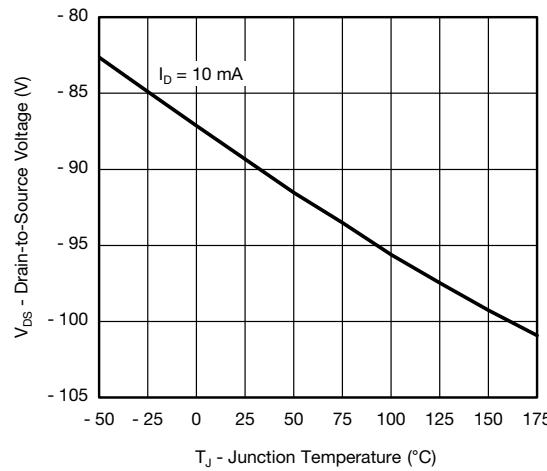
SPECIFICATIONS ($T_C = 25^\circ\text{C}$, unless otherwise noted)									
PARAMETER	SYMBOL	TEST CONDITIONS			MIN.	TYP.	MAX.		
Static									
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0\text{ V}$, $I_D = -250\text{ }\mu\text{A}$	- 80	-	-	V			
Gate-Source Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}$, $I_D = -250\text{ }\mu\text{A}$	- 1.5	- 2.0	- 2.5				
Gate-Source Leakage	I_{GSS}	$V_{DS} = 0\text{ V}$, $V_{GS} = \pm 20\text{ V}$	-	-	± 100	nA			
Zero Gate Voltage Drain Current	I_{DSS}	$V_{GS} = 0\text{ V}$, $V_{DS} = -80\text{ V}$	-	-	- 1	μA			
		$V_{GS} = 0\text{ V}$, $V_{DS} = -80\text{ V}$, $T_J = 125^\circ\text{C}$	-	-	- 50				
		$V_{GS} = 0\text{ V}$, $V_{DS} = -80\text{ V}$, $T_J = 175^\circ\text{C}$	-	-	- 250				
On-State Drain Current ^a	$I_{D(\text{on})}$	$V_{GS} = -10\text{ V}$, $V_{DS} \leq -5\text{ V}$	- 50	-	-	A			
Drain-Source On-State Resistance ^a	$R_{DS(\text{on})}$	$V_{GS} = -10\text{ V}$, $I_D = -12.5\text{ A}$	-	0.020	0.025	Ω			
		$V_{GS} = -10\text{ V}$, $I_D = -12.5\text{ A}$, $T_J = 125^\circ\text{C}$	-	-	0.044				
		$V_{GS} = -10\text{ V}$, $I_D = -12.5\text{ A}$, $T_J = 175^\circ\text{C}$	-	-	0.055				
		$V_{GS} = -4.5\text{ V}$, $I_D = -10.5\text{ A}$	-	0.025	0.031				
Forward Transconductance ^b	g_{fs}	$V_{DS} = -15\text{ V}$, $I_D = -12.5\text{ A}$	-	38	-	S			
Dynamic^b									
Input Capacitance	C_{iss}	$V_{GS} = 0\text{ V}$	$V_{DS} = -25\text{ V}$, $f = 1\text{ MHz}$	-	4279	5350	pF		
Output Capacitance	C_{oss}			-	356	445			
Reverse Transfer Capacitance	C_{rss}			-	239	300			
Total Gate Charge ^c	Q_g	$V_{GS} = -10\text{ V}$	$V_{DS} = -40\text{ V}$, $I_D = -12.5\text{ A}$	-	91	137	nC		
Gate-Source Charge ^c	Q_{gs}			-	8.2	-			
Gate-Drain Charge ^c	Q_{gd}			-	24	-			
Gate Resistance	R_g	$f = 1\text{ MHz}$			1.60	3.26	5.00	Ω	
Turn-On Delay Time ^c	$t_{d(\text{on})}$	$V_{DD} = -40\text{ V}$, $R_L = 3.2\text{ }\Omega$ $I_D \geq -12.5\text{ A}$, $V_{GEN} = -10\text{ V}$, $R_g = 1\text{ }\Omega$		-	10	15	ns		
Rise Time ^c	t_r			-	11	17			
Turn-Off Delay Time ^c	$t_{d(\text{off})}$			-	71	107			
Fall Time ^c	t_f			-	16	24			
Source-Drain Diode Ratings and Characteristics^b									
Pulsed Current ^a	I_{SM}				-	-	- 120	A	
Forward Voltage	V_{SD}	$I_F = -10.5\text{ A}$, $V_{GS} = 0\text{ V}$			-	- 0.82	- 1.5	V	

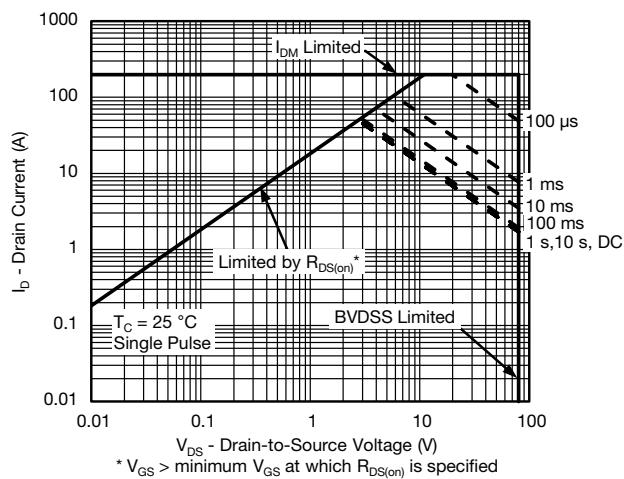
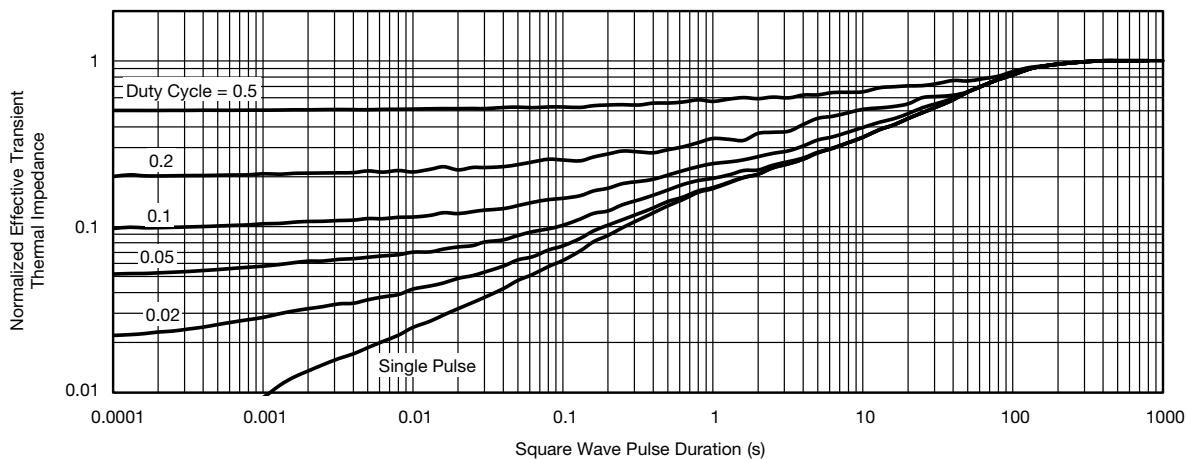
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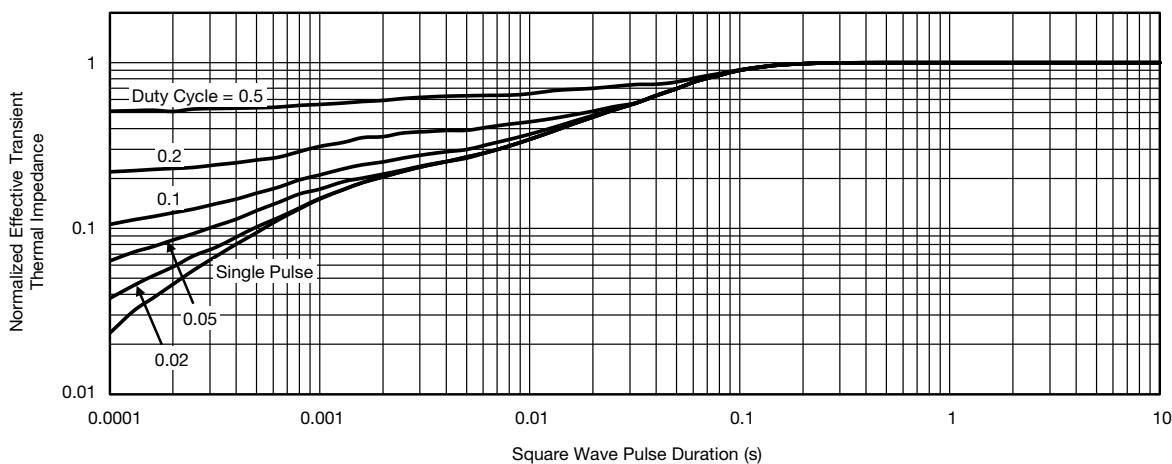
- Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\text{ \%}$.
- Guaranteed by design, not subject to production testing.
- Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

Output Characteristics

Transfer Characteristics

Transfer Characteristics

Transconductance

On-Resistance vs. Drain Current

Capacitance

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

Gate Charge

On-Resistance vs. Junction Temperature

Source Drain Diode Forward Voltage

On-Resistance vs. Gate-to-Source Voltage

Threshold Voltage
Drain Source Breakdown vs. Junction Temperature

THERMAL RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

Safe Operating Area

Normalized Thermal Transient Impedance, Junction-to-Ambient

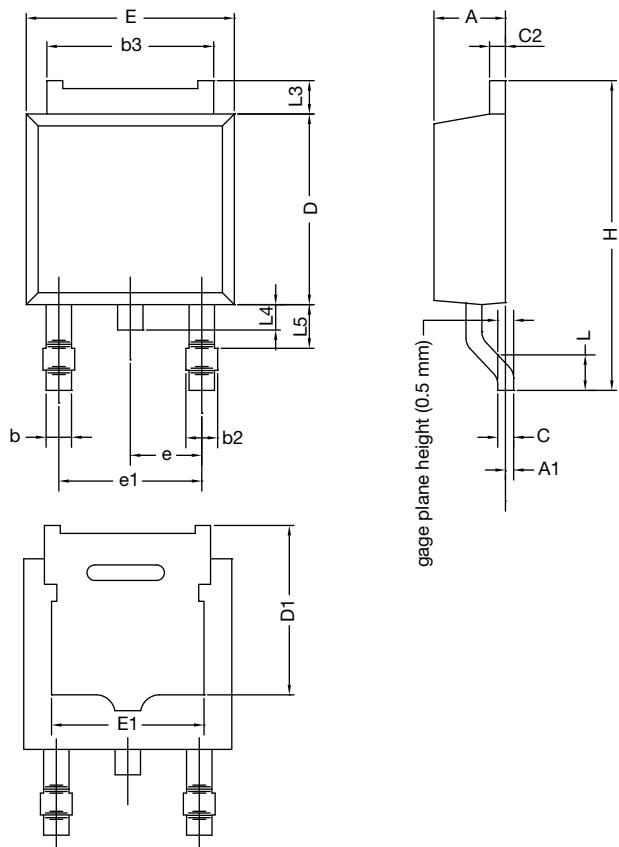
THERMAL RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25°C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25°C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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TO-252AA Case Outline



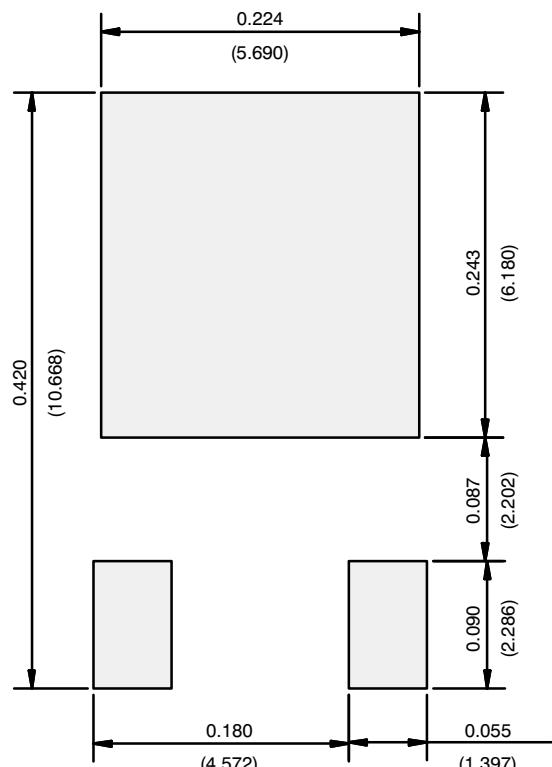
DIM.	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	2.18	2.38	0.086	0.094
A1	-	0.127	-	0.005
b	0.64	0.88	0.025	0.035
b2	0.76	1.14	0.030	0.045
b3	4.95	5.46	0.195	0.215
C	0.46	0.61	0.018	0.024
C2	0.46	0.89	0.018	0.035
D	5.97	6.22	0.235	0.245
D1	4.10	-	0.161	-
E	6.35	6.73	0.250	0.265
E1	4.32	-	0.170	-
H	9.40	10.41	0.370	0.410
e	2.28 BSC		0.090 BSC	
e1	4.56 BSC		0.180 BSC	
L	1.40	1.78	0.055	0.070
L3	0.89	1.27	0.035	0.050
L4	-	1.02	-	0.040
L5	1.01	1.52	0.040	0.060

ECN: T13-0592-Rev. A, 02-Sep-13
DWG: 6019

Note

- Dimension L3 is for reference only.

RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



**Recommended Minimum Pads
Dimensions in Inches/(mm)**

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